

International
IR Rectifier

SAFEIR Series
16TTS..FP

PHASE CONTROL SCR TO-220 FULLPAK

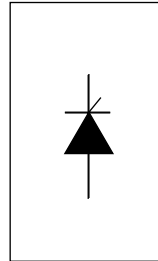
Description/Features

The 16TTS..FP **SAFEIR** series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125° C junction temperature.

Typical applications are in input rectification (soft start) and these products are designed to be used with International Rectifier input diodes, switches and output rectifiers which are available in identical package outlines.

Fully isolated package ($V_{INS} = 2500 V_{RMS}$)

UL E78996 approved 



$$\begin{aligned} V_T &< 1.4V @ 10A \\ I_{TSM} &= 200A \\ V_{RRM} &800 \text{ to } 1600V \end{aligned}$$

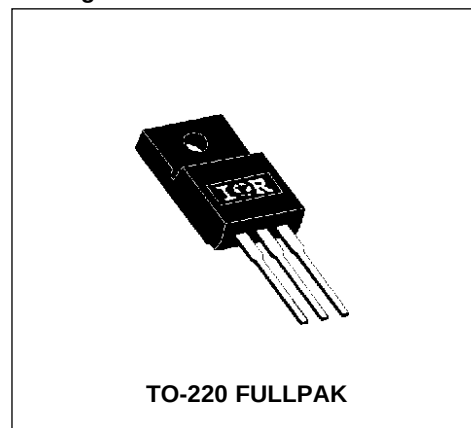
Output Current in Typical Applications

Applications	Single-phase Bridge	Three-phase Bridge	Units
Capacitive input filter $T_A = 55^\circ\text{C}$, $T_J = 125^\circ\text{C}$, common heatsink of 1°C/W	13.5	17	A

Major Ratings and Characteristics

Characteristics	16TTS..FP	Units
$I_{T(AV)}$ Sinusoidal waveform	10	A
I_{RMS}	16	A
V_{RRM}/V_{DRM}	upto1600	V
I_{TSM}	200	A
V_T @ 10 A, $T_J = 25^\circ\text{C}$	1.4	V
dv/dt	500	V/ μs
di/dt	150	A/ μs
T_J range	-40 to 125	$^\circ\text{C}$

Package Outline



16TTS..FP *SAFEIR* Series

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Voltage Ratings

Part Number	V_{RRM} , maximum peak reverse voltage V	V_{DRM} , maximum peak direct voltage V	I_{RRM}/I_{DRM} 125°C mA
16TTS08FP	800	800	10
16TTS12FP	1200	1200	
16TTS16FP	1600	1600	

Absolute Maximum Ratings

Parameters		16TTS..FP		Units	Conditions	
I _{T(AV)}	Max. Average On-state Current	10		A	@ T _C =95°C, 180° conduction half sine wave	
I _{RMS}	Max. RMS On-state Current	16				
I _{TSM}	Max. Peak One Cycle Non-Repetitive	170			10ms Sine pulse, rated V _{RRM} applied	
	Surge Current	200			10ms Sine pulse, no voltage reappplied	
I ² t	Max. I ² t for fusing	144		A ² s	10ms Sine pulse, rated V _{RRM} applied	
		200			10ms Sine pulse, no voltage reappplied	
I ² √t	Max. I ² √t for fusing	2000		A ² √s	t=0.1 to 10ms, no voltage reappplied	
V _{TM}	Max. On-state Voltage Drop	1.4		V	@ 10A, T _j = 25°C	
r _t	On-state Slope Resistance	24.0		mΩ	T _j = 125°C	
V _{T(TO)}	Threshold Voltage	1.1		V		
I _{RM} /I _{DM}	Max. Reverse and Direct Leakage Current	0.5		mA	T _j = 25 °C	V _R = rated V _{RRM} / V _{DRM}
		10			T _j = 125 °C	
I _H	Holding Current	Typ.	Max.	mA	Anode Supply = 6V, Resistive load, Initial I _T =1A 16TTS08FP, 16TTS12FP 16TTS16FP	
		--	100			
		100	150			
I _L	Max. Latching Current	200		mA	Anode Supply =6V, Resistive load	
dv/dt	Max. Rate of Rise of off-state Voltage	500		V/μs		
di/dt	Max. Rate of Rise of turned-on Current	150		A/μs		

Triggering

Parameters	16TTS..FP	Units	Conditions
P_{GM} Max. peak Gate Power	8.0	W	
$P_{G(AV)}$ Max. average Gate Power	2.0		
$+I_{GM}$ Max. peak positive Gate Current	1.5	A	
$-V_{GM}$ Max. peak negative Gate Voltage	10	V	
I_{GT} Max. required DC Gate Current to trigger	90	mA	Anode supply = 6V, resistive load, $T_J = -10^\circ\text{C}$
	60		Anode supply = 6V, resistive load, $T_J = 25^\circ\text{C}$
	35		Anode supply = 6V, resistive load, $T_J = 125^\circ\text{C}$
V_{GT} Max. required DC Gate Voltage to trigger	3.0	V	Anode supply = 6V, resistive load, $T_J = -10^\circ\text{C}$
	2.0		Anode supply = 6V, resistive load, $T_J = 25^\circ\text{C}$
	1.0		Anode supply = 6V, resistive load, $T_J = 125^\circ\text{C}$
V_{GD} Max. DC Gate Voltage not to trigger	0.2		$T_J = 125^\circ\text{C}$, $V_{DRM} = \text{rated value}$
I_{GD} Max. DC Gate Current not to trigger	2.0	mA	$T_J = 125^\circ\text{C}$, $V_{DRM} = \text{rated value}$

Switching

Parameters	16TTS..FP	Units	Conditions
t_{gt} Typical turn-on time	0.9	μs	$T_J = 25^\circ\text{C}$
t_{rr} Typical reverse recovery time	4		$T_J = 125^\circ\text{C}$
t_q Typical turn-off time	110		

Thermal-Mechanical Specifications

Parameters	16TTS..FP	Units	Conditions
T_J Max. Junction Temperature Range	-40 to 125	$^\circ\text{C}$	
T_{stg} Max. Storage Temperature Range	-40 to 125		
R_{thJC} Max. Thermal Resistance Junction to Case	1.5	$^\circ\text{C/W}$	DC operation
R_{thJA} Max. Thermal Resistance Junction to Ambient	62		
R_{thCS} Typ. Thermal Resistance Case to Heatsink	1.5		Mounting surface, smooth and greased
wt Approximate Weight	2 (0.07)	g (oz.)	
T Mounting Torque	Min.	6 (5)	Kg-cm (lbf-in)
	Max.	12 (10)	
Case Style	TO-220FULLPAK		(94/V0)

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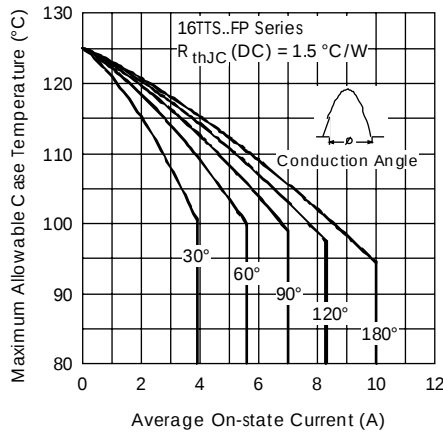


Fig. 1 - Current Rating Characteristics

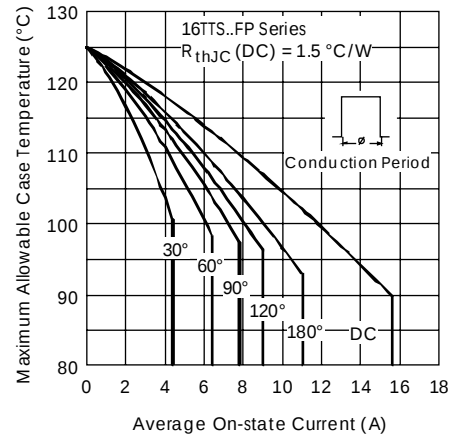


Fig. 2 - Current Rating Characteristics

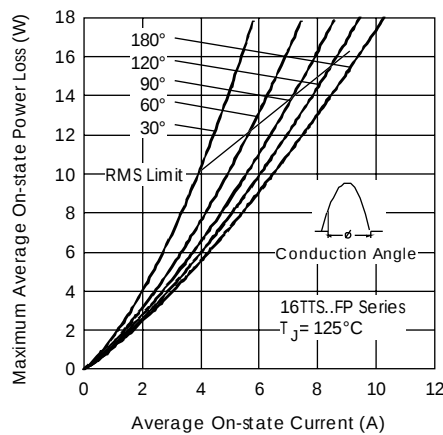


Fig. 3 - On-state Power Loss Characteristics

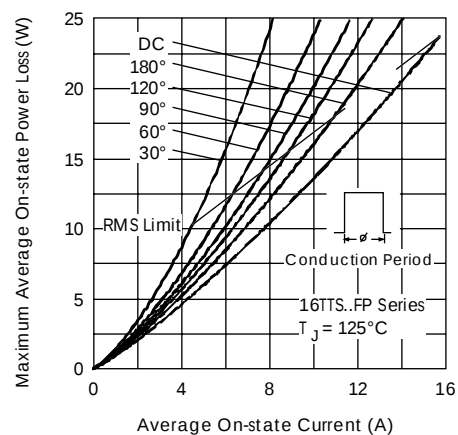


Fig. 4 - On-state Power Loss Characteristics

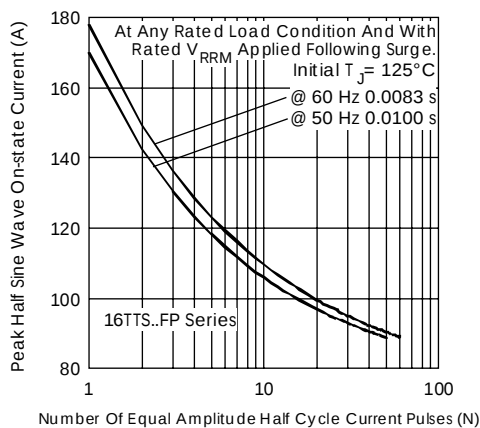


Fig. 5 - Maximum Non-Repetitive Surge Current

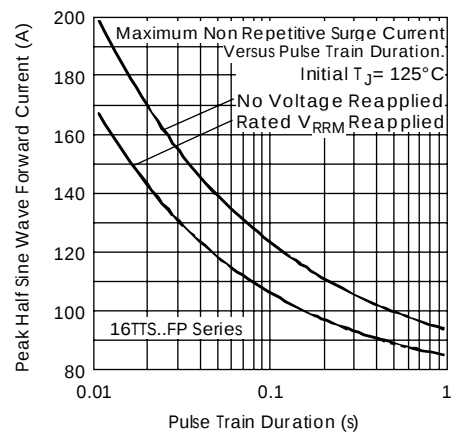


Fig. 6 - Maximum Non-Repetitive Surge Current

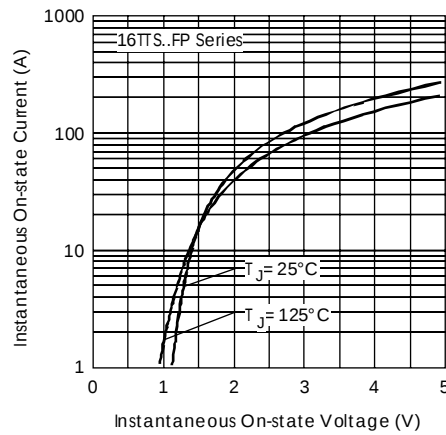


Fig. 7 - On-state Voltage Drop Characteristics

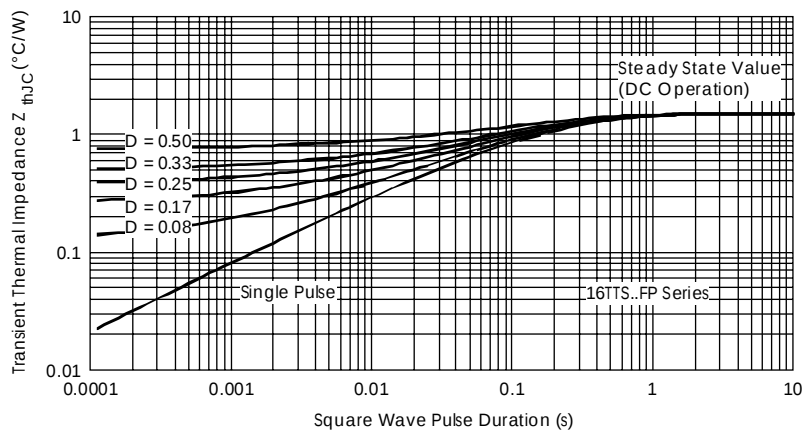


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

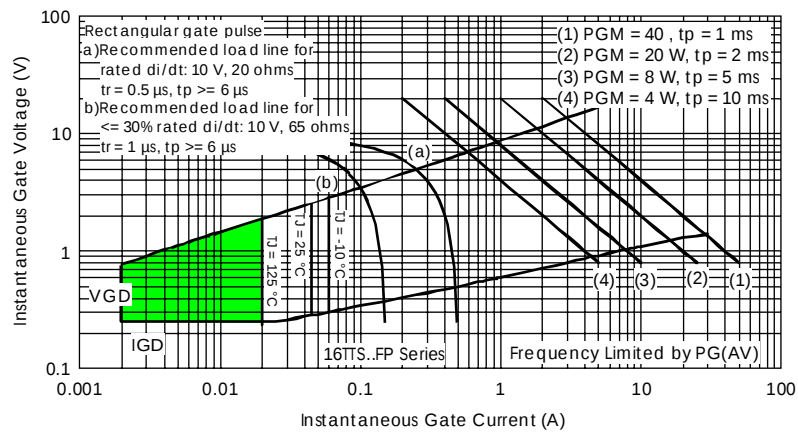


Fig. 9 - Gate Characteristics

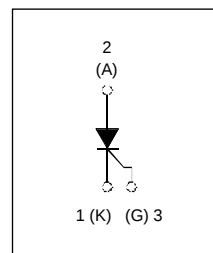
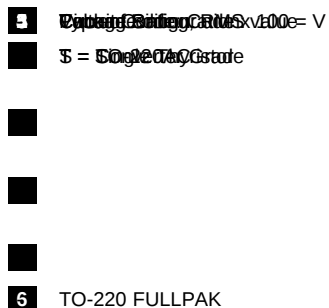
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Outline Table



Ordering Information Table



RRM — 08 = 800V
12 = 1200V
16 = 1600V

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WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245 U.S.A. Tel: (310) 322 3331. Fax: (310) 322 3332.
EUROPEAN HEADQUARTERS: Hurst Green, Oxted, Surrey RH8 9BB, U.K. Tel: ++ 44 1883 732020. Fax: ++ 44 1883 733408.
IR CANADA: 15 Lincoln Court, Brampton, Markham, Ontario L6T3Z2. Tel: (905) 453 2200. Fax: (905) 475 8801.
IR GERMANY: Saalburgstrasse 157, 61350 Bad Homburg. Tel: ++ 49 6172 96590. Fax: ++ 49 6172 965933.
IR ITALY: Via Liguria 49, 10071 Borgaro, Torino. Tel: ++ 39 11 4510111. Fax: ++ 39 11 4510220.
IR FAR EAST: K&H Bldg., 2F, 30-4 Nishi-Ikebukuro 3-Chome, Toshima-Ku, Tokyo, Japan 171. Tel: 81 3 3983 0086.
IR SOUTHEAST ASIA: 1 Kim Seng Promenade, Great World City West Tower, 13-11, Singapore 237994. Tel: ++ 65 838 4630.
IR TAIWAN: 16 Fl. Suite D.207, Sec. 2, Tun Haw South Road, Taipei, 10673, Taiwan. Tel: 886 2 2377 9936.

Fax-On-Demand: +44 1883 733420

Data and specifications subject to change without notice.



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